

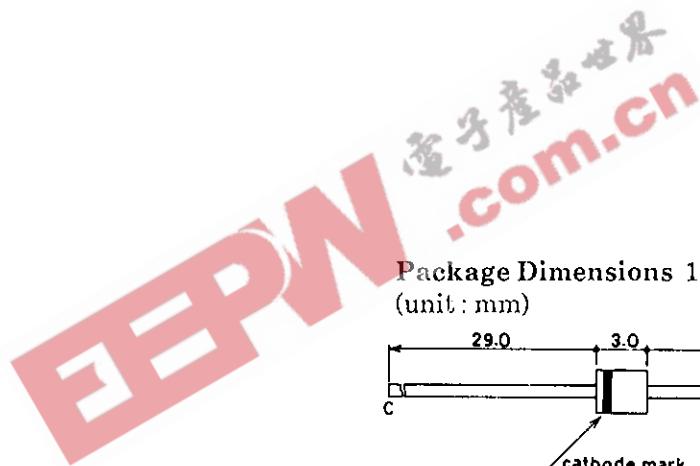
SANYO	No.4703	DZF6.8 to 36
		Silicon Diffused Junction Type
		1W Zener Diode

Features

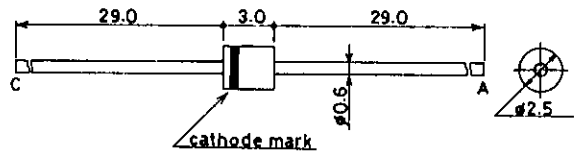
- Plastic mold package.
- Voltage regulator use.
- Allowable power dissipation : P=1W.
- Subdivided voltage range : 6.8 to 36V.
- Zener voltage tolerance: ±10%

Absolute Maximum Ratings at Ta = 25°C

			unit
Allowable Power Dissipation	P	1.0	W
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-40 to +150	°C



Package Dimensions 1261
(unit : mm)



C : Cathode
A : Anode

■ No products described or contained herein are intended for use in surgical implants, life-support systems, aerospace equipment, nuclear power control systems, vehicles, disaster/crime-prevention equipment and the like, the failure of which may directly or indirectly cause injury, death or property loss.

■ Anyone purchasing any products described or contained herein for an above-mentioned use shall:

- ① Accept full responsibility and indemnify and defend SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors and all their officers and employees, jointly and severally, against any and all claims and litigation and all damages, cost and expenses associated with such use;
- ② Not impose any responsibility for any fault or negligence which may be cited in any such claim or litigation on SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors or any of their officers and employees jointly or severally.

■ Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

DZF6.8 to 36

Electrical Characteristics at $T_a = 25^\circ\text{C}$

Type No.	Zener Characteristics					Temperature Coefficient γ_z		Forward Voltage V_F		Reverse Current	
	Zener Voltage V_Z			Dynamic Resistance r_d	Current at which V_Z, r_d are measured I_Z	γ_z		Current at which V_F is measured	Reverse Current I_R	Voltage at which I_R is measured	
	[V]					[mV/°C]					
	min	typ	max	max		typ	max	max	max		
DZF6.8	6.2	6.8	7.4	60		10	3	4	1.2	0.2	10
DZF7.5	6.8	7.5	8.3	30	10	4	5	1.2	0.2	10	4.5
DZF8.2	7.4	8.2	9.1	30	10	4	6	1.2	0.2	10	4.9
DZF9.1	8.2	9.1	10.1	30	10	5	8	1.2	0.2	10	5.5
DZF10	9.0	10	11.0	30	10	6	9	1.2	0.2	10	6.0
DZF11	9.9	11	12.1	30	10	7	11	1.2	0.2	10	7.0
DZF12	10.8	12	13.2	30	10	8	13	1.2	0.2	10	8.0
DZF13	11.7	13	14.3	30	10	9	14	1.2	0.2	10	9.0
DZF15	13.5	15	16.5	30	10	11	17	1.2	0.2	10	10.0
DZF16	14.4	16	17.6	30	10	12	19	1.2	0.2	10	11.0
DZF18	16.2	18	19.8	30	10	14	23	1.2	0.2	10	13.0
DZF20	18.0	20	22.0	30	10	16	26	1.2	0.2	10	14.0
DZF22	19.8	22	24.2	30	10	18	28	1.2	0.2	10	16.0
DZF24	21.6	24	26.4	30	10	20	32	1.2	0.2	10	17.0
DZF27	24.3	27	29.7	30	10	23	36	1.2	0.2	10	19.0
DZF30	27.0	30	33.0	30	10	25	40	1.2	0.2	10	21.0
DZF33	29.7	33	36.3	30	10	26	41	1.2	0.2	10	26.4
DZF36	32.4	36	39.6	30	9	28	45	1.2	0.2	10	28.8

